

UNISONIC TECHNOLOGIES CO., LTD

UD9K

Preliminary

GENERAL PURPOSE (DUAL DIGITAL TRANSISTOR)

DESCRIPTION

The UTC **UD9K** is an dual transistor; it uses UTC's advanced technology to provide the customers with low collector -emitter saturation voltage, etc.

The UTC **UD9K** is suitable for switching, inverter circuit and driver circuit applications.

FEATURES

- * Both the DTA114Y chip and DTC114Y chip in a SOT-363 package.
- * NPN/PNP silicon transistor(Built-in resistor type)
- * Low collector-emitter saturation voltage
- * With built-in bias resistors
- * Simplify circuit design

EQUIVALENT CIRCUIT



ORDERING INFORMATION

Ordering Number		Package		Pi	Deaking				
				2	3	4	5	6	Packing
UD9KG-AL6-R SO		DT-363	E1	B1	C2	E2	B2	C1	Tape Reel
Note: Pin Assignment: E: Emitter B: Base	Note: Pin Assignment: E: Emitter B: Base C: Collector								
UD9KG-AL6-R (1)Packing Type (2)Package Type (3)Green Package		(1) R: Ta (2) AL6: \$ (3) G: Ha	pe Re SOT- Iloger	eel 363 n Free	e and	Lead	Free	9	

MARKING





■ ABSOLUTE MAXIMUM RATINGS (T_A=25°C, unless otherwise specified)

		RAT			
PARAMETER	STMBOL	TR1 (NPN)	TR2 (PNP)	UNIT	
Supply Voltage	Vcc	50	-50	V	
Input Voltage	V _{IN}	-6 ~ +40	-40 ~ +6	V	
Output Current	lout	70	-70	mA	
	I _{C(MAX)}	100	-100	mA	
Total Power Dissipation (Note 2)	PD	1:	mW		
Junction Temperature	TJ	+1	°C		
Storage Temperature	T _{STG}	-55 ~	°C		

Notes: 1. Absolute maximum ratings are those values beyond which the device could be permanently damaged. Absolute maximum ratings are stress ratings only and functional device operation is not implied.

2. 120mW per element must not be exceeded.

ELECTRICAL SPECIFICATIONS (T_A=25°C, unless others specified)

TR1 (NPN)

PARAMETER	SYMBOL	TEST CONDITIONS	MIN	TYP	MAX	UNIT
Input Voltage	V _{IN(OFF)}	V _{CC} =5V, I _{OUT} =100µA			0.3	V
	V _{IN(ON)}	V _{OUT} =0.3V, I _{OUT} =1mA	1.4			V
Output Voltage	V _{OUT(ON)}	I _{OUT} /I _{IN} =5mA/0.25mA		0.1	0.3	V
Input Current	I _{IN}	V _{IN} =5V			0.88	mA
Output Current	I _{OUT(OFF)}	V _{CC} =50V, V _{IN} =0V			0.5	μA
DC Current Gain	h _{FE}	V _{OUT} =5V, I _{OUT} =5mA	68			
Input Resistance	R ₁		7	10	13	KΩ
Resistor Ratio	$\frac{R_2}{R_1}$		3.7	4.7	5.7	
Transition Frequency	f⊤	V _{CE} =10V, I _E =–5mA, f=100MHz		250		MHz

Note: Transition frequency of the device

TR2 (PNP)

PARAMETER	SYMBOL	TEST CONDITIONS	MIN	TYP	MAX	UNIT
Input Voltage	$V_{IN(OFF)}$	V _{CC} =-5V, Ι _{ΟUT} =-100μΑ			-0.3	V
	V _{IN(ON)}	V _{OUT} =-0.3V, I _{OUT} =-1mA	-1.4			V
Output Voltage	V _{OUT (ON)}	I _{OUT} /I _{IN} =-5mA/-0.25mA		-0.1	-0.3	V
Input Current	I _{IN}	V _{IN} =-5V			-0.88	mA
Output Current	IOUT(OFF)	V _{CC} =-50V, V _{IN} =0V			-0.5	μA
DC Current Gain	h_{FE}	V _{OUT} =-5V, I _{OUT} =-5mA	68			
Input Resistance	R ₁		7	10	13	KΩ
Resistance Ratio	R_2/R_1		3.7	4.7	5.7	
Transition Frequency	f⊤	V _{CE} =-10V, I _E =5mA, f=100MHz(Note)		250		MHz

Note: Transition frequency of the device.



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